

504.

标题 : Photoconductive Emission and Detection of Terahertz Pulsed Radiation Using Semiconductors and Semiconductor Devices

作者: Tani, M (Tani, Masahiko); Yamamoto, K (Yamamoto, Kohji); Estacio, ES (Estacio, Elmer S.); Que, CT (Que, Christopher T.); Nakajima, H (Nakajima, Hidekazu); Hibi, M (Hibi, Masakazu); Miyamaru, F (Miyamaru, Fumiaki); Nishizawa, S (Nishizawa, Seizi); Hangyo, M (Hangyo, Masanori)

来源出版物: JOURNAL OF INFRARED MILLIMETER AND TERAHERTZ WAVES 卷: 33

期: 4 页: 393-404 DOI: 10.1007/s10762-012-9882-1 出版年: APR 2012

在 Web of Science 中的被引频次: 0

被引频次合计: 0

引用的参考文献数: 43

摘要: Recent studies on the techniques and development of photoconductive (PC) semiconductor devices for efficient generation and detection of terahertz (THz) pulsed radiation are reported. Firstly, the optimization of PC antenna design is discussed. The PC detection of THz pulsed radiation using low-temperature grown GaAs with 1.55- $\mu$ m wavelength probe is then described. Finally, the enhancement of THz radiation from InSb by using a coupling lens and magnetic field is investigated. These results reveal valuable insights on the design of an efficient, compact, and cost-effective THz time-domain spectroscopy system based on 1.55- $\mu$ m fs laser sources.

入藏号: WOS:000302075900002

语种: English

文献类型: Article

作者关键词: Terahertz; Photoconductive antenna; Low-temperature-grown GaAs; 1.55- $\mu$ m femtosecond laser; InSb; Lens coupling; Magnetic field enhancement

KeyWords Plus: TIME-DOMAIN SPECTROSCOPY; 1.55 MU-M; MOLECULAR-BEAM EPITAXY; THZ RADIATION; GAAS; SUBPICOSECOND; GENERATION; ANTENNAS; TEMPERATURES; EXCITATION

地址: [Tani, Masahiko; Yamamoto, Kohji; Estacio, Elmer S.; Que, Christopher T.; Nakajima, Hidekazu; Hibi, Masakazu] Univ Fukui, Res Ctr Dev Far Infrared Reg, Fukui 9108507, Japan

[Miyamaru, Fumiaki] Shinshu Univ, Fac Sci, Dept Phys, Matsumoto, Nagano 3908621, Japan

[Nishizawa, Seizi] Adv Infrared Spect Co Ltd, Hachioji, Tokyo 1930835, Japan

[Hangyo, Masanori] Osaka Univ, Inst Laser Engn, Suita, Osaka 5650871, Japan

通讯作者地址: Tani, M (通讯作者), Univ Fukui, Res Ctr Dev Far Infrared Reg, 3-9-1 Bunkyo, Fukui 9108507, Japan

电子邮件地址: tani@fir.u-fukui.ac.jp

出版商: SPRINGER

出版商地址: 233 SPRING ST, NEW YORK, NY 10013 USA

Web of Science 分类: Engineering, Electrical & Electronic; Optics; Physics, Applied

学科类别: Engineering; Optics; Physics

IDS 号: 916CW

ISSN: 1866-6892

29 字符的来源出版物名称缩写: J INFRARED MILLIM TE

ISO 来源出版物缩写: J. Infrared Millim. Terahertz Waves

来源出版物页码计数: 12